

Description

The SX100N04NF uses advanced technology to provide excellent $R_{DS(ON)}$, low gate charge and operation with gate voltages as low as 4.5V. This device is suitable for use as a Battery protection or in other Switching application.

General Features

$V_{DS} = 40V$ $I_D = 100A$

$R_{DS(ON)} < 3.2m\Omega$ @ $V_{GS}=10V$

$C_{iss} \approx 2600PF$

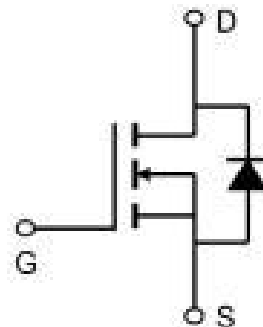
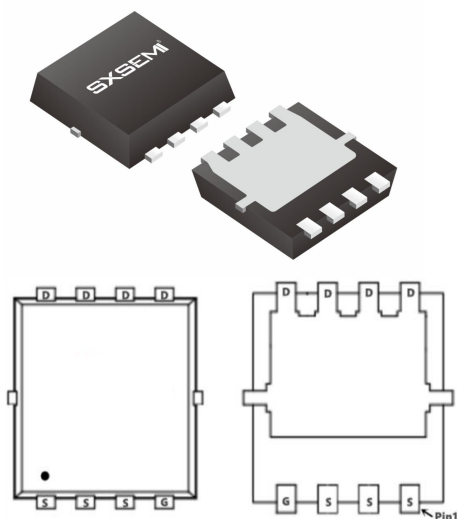
Application

Boost driver

Brushless motor

BLDC

PDFN5*6-8L



Absolute Maximum Ratings ($T_c=25^\circ C$ unless otherwise noted)

Symbol	Parameter	Rating	Units
V_{DS}	Drain-Source Voltage	40	V
V_{GS}	Gate-Source Voltage	± 20	V
$I_{D@TC=25^\circ C}$	Continuous Drain Current, $V_{GS} @ 10V$	100	A
$I_{D@TC=100^\circ C}$	Continuous Drain Current, $V_{GS} @ 10V$	71	A
I_{DM}	Pulsed Drain Current ²	240	A
E_{AS}	Single Pulse Avalanche Energy ³	345	mJ
I_{AS}	Avalanche Current	54	A
$P_{D@TC=25^\circ C}$	Total Power Dissipation ⁴	22	W
T_{STG}	Storage Temperature Range	-55 to 150	$^\circ C$
T_J	Operating Junction Temperature Range	-55 to 150	$^\circ C$
$R_{\theta JA}$	Thermal Resistance Junction-Ambient 1	25	$^\circ C/W$
$R_{\theta JC}$	Thermal Resistance Junction-Case ¹	1.7	$^\circ C/W$

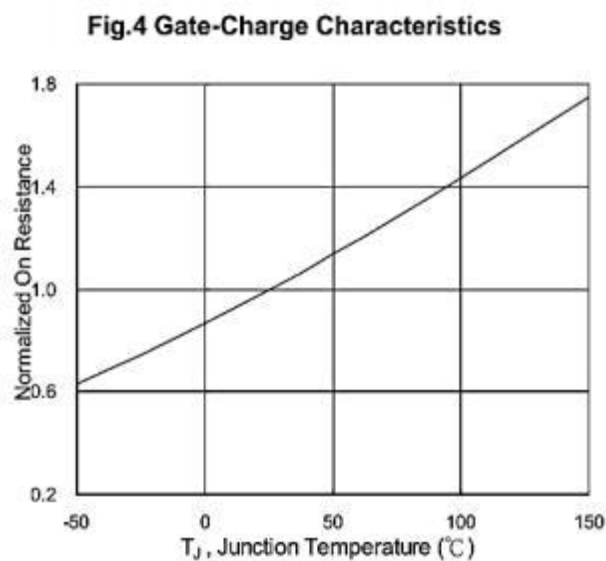
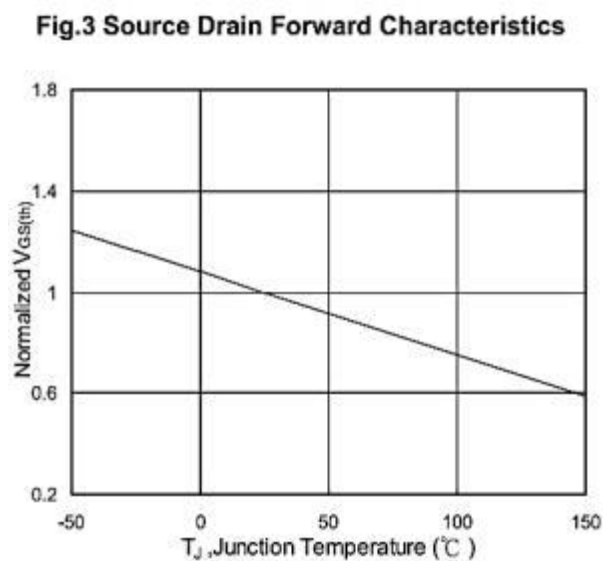
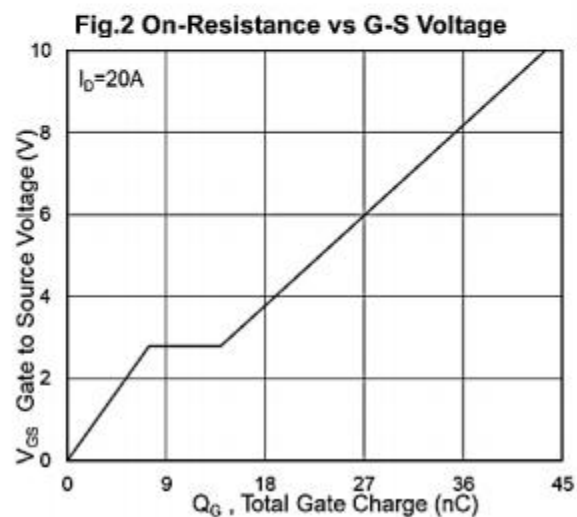
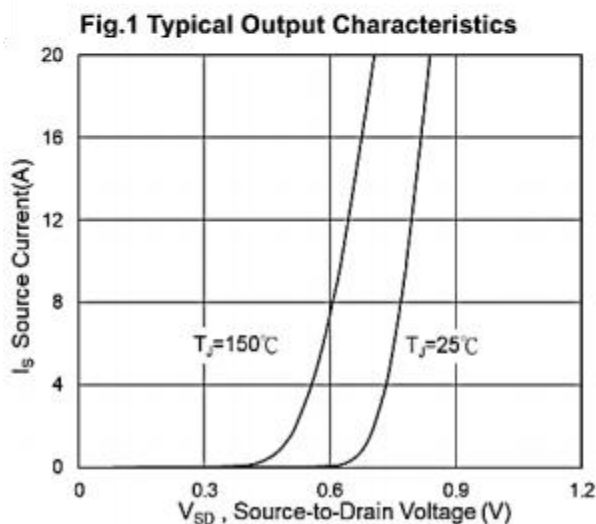
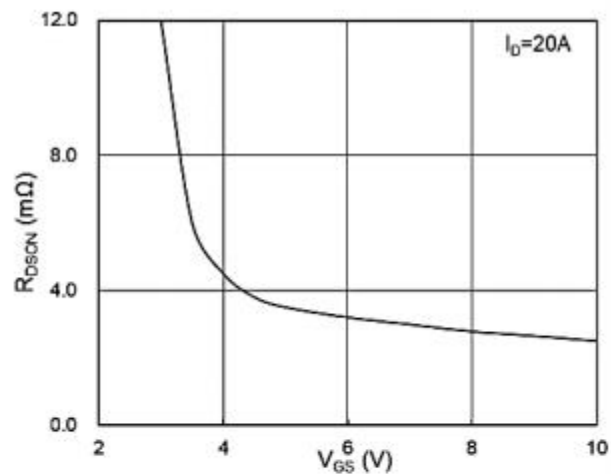
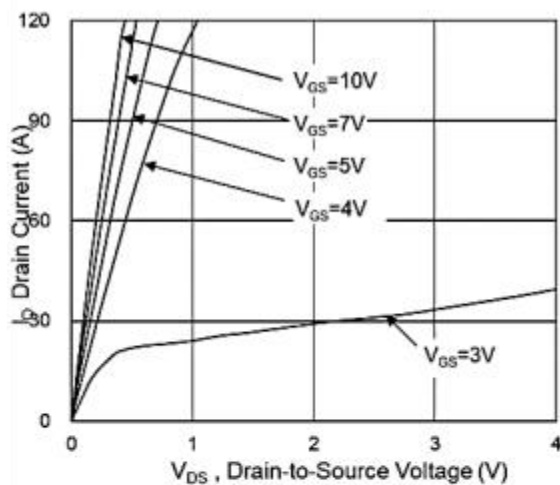
Electrical Characteristics (T_J=25°C, unless otherwise noted)

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
BVDSS	Drain-Source Breakdown Voltage	V _{GS} =0V , I _D =250uA	40	44	---	V
RDS(ON)	Static Drain-Source On-Resistance ²	V _{GS} =10V , I _D =20A	---	2.1	3.2	mΩ
		V _{GS} =4.5V , I _D =15A	---	2.7	5.3	
VGS(th)	Gate Threshold Voltage	V _{GS} =V _{DS} , I _D =250uA	1.2	1.7	2.5	V
IDSS	Drain-Source Leakage Current	V _{DS} =40V , V _{GS} =0V , T _J =25°C	---	---	1	uA
IDSS	Drain-Source Leakage Current	V _{DS} =40V , V _{GS} =0V , T _J =55°C	---	---	5	
IGSS	Gate-Source Leakage Current	V _{GS} =±20V , V _{DS} =0V	---	---	±100	nA
gfs	Forward Transconductance	V _{DS} =5V , I _D =20A	---	75	---	S
R _g	Gate Resistance	V _{DS} =0V , V _{GS} =0V , f=1MHz	---	1.5	---	Ω
Q _g	Total Gate Charge (4.5V)	V _{DS} =20V , V _{GS} =4.5V , I _D =20A	---	22.7	---	nC
Q _{gs}	Gate-Source Charge		---	7.5	---	
Q _{gd}	Gate-Drain Charge		---	5.5	---	
Td(on)	Turn-On Delay Time	V _{DD} =20V , V _{GS} =10V , R _G =3Ω , I _D =20A	---	10	---	ns
T _r	Rise Time		---	5	---	
Td(off)	Turn-Off Delay Time		---	33	---	
T _f	Fall Time		---	6.5	---	
Ciss	Input Capacitance	V _{DS} =20V , V _{GS} =0V , f=1MHz	---	2600	---	pF
Coss	Output Capacitance		---	899	---	
Crss	Reverse Transfer Capacitance		---	71	---	
IS	Continuous Source Current ^{1,5}	V _G =V _D =0V , Force Current	---	---	30	A
VSD	Diode Forward Voltage ²	V _{GS} =0V , I _S =1A , T _J =25°C	---	---	1	V

Note :

- 1、The data tested by surface mounted on a 1 inch 2 FR-4 board with 2OZ copper.
- 2、The data tested by pulsed , pulse width ≤ 300us , duty cycle ≤ 2%
- 3、The EAS data shows Max. rating . The test condition is VDD =32V,VGS =10V,L=0.1mH,IAS =54A
- 4、The power dissipation is limited by 150°C junction temperature
- 5、The data is theoretically the same as I D and I DM , in real applications , should be limited by total power dissipation.

Typical Characteristics



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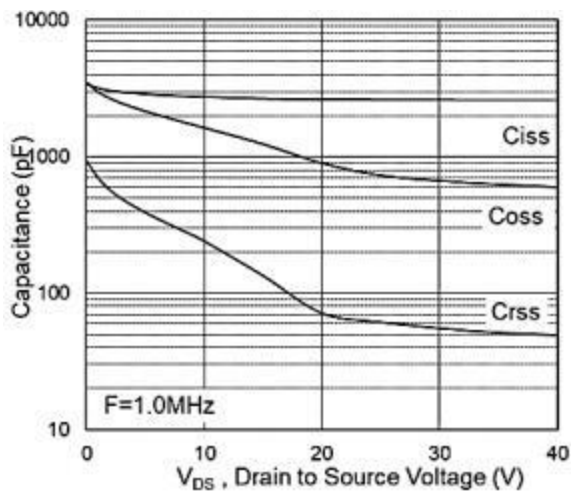


Fig.7 Capacitance

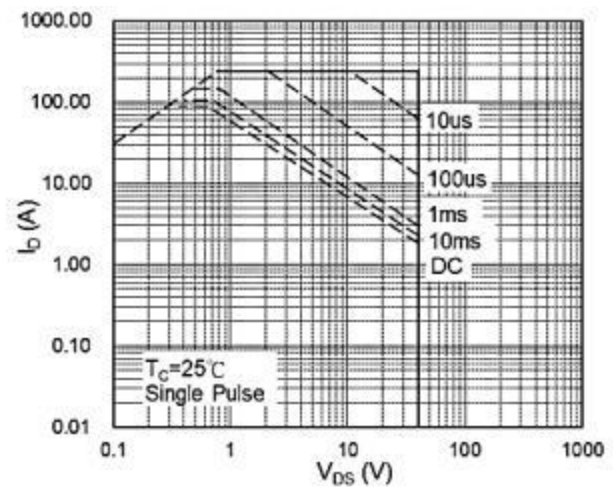


Fig.8 Safe Operating Area

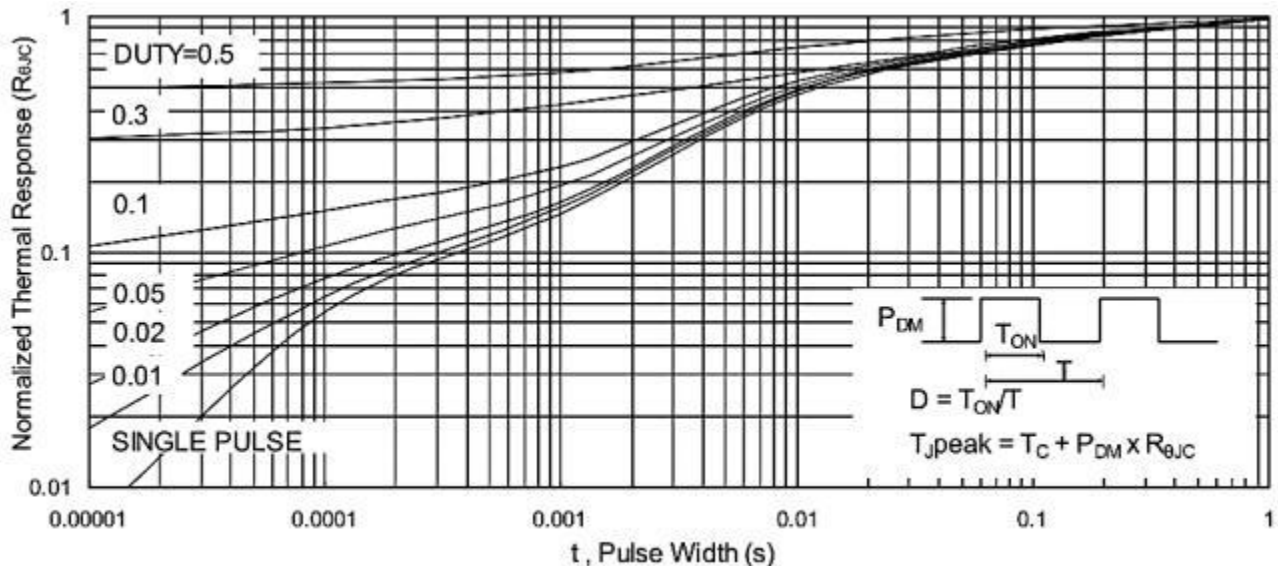


Fig.9 Normalized Maximum Transient Thermal Impedance

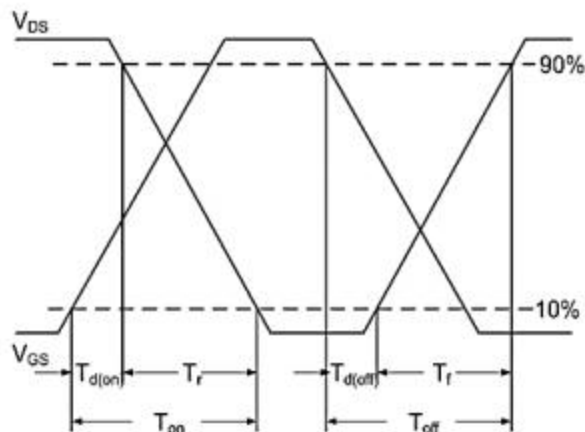


Fig.10 Switching Time Waveform

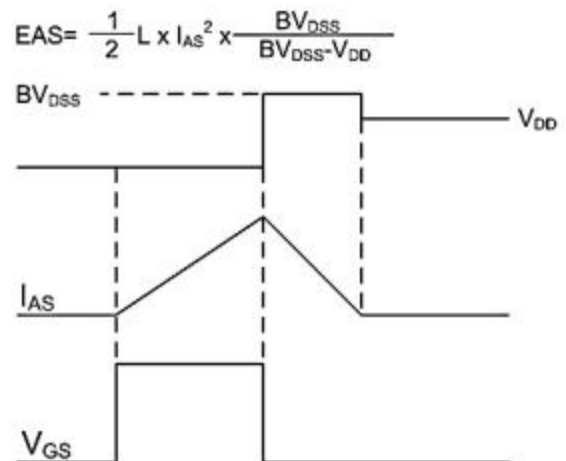
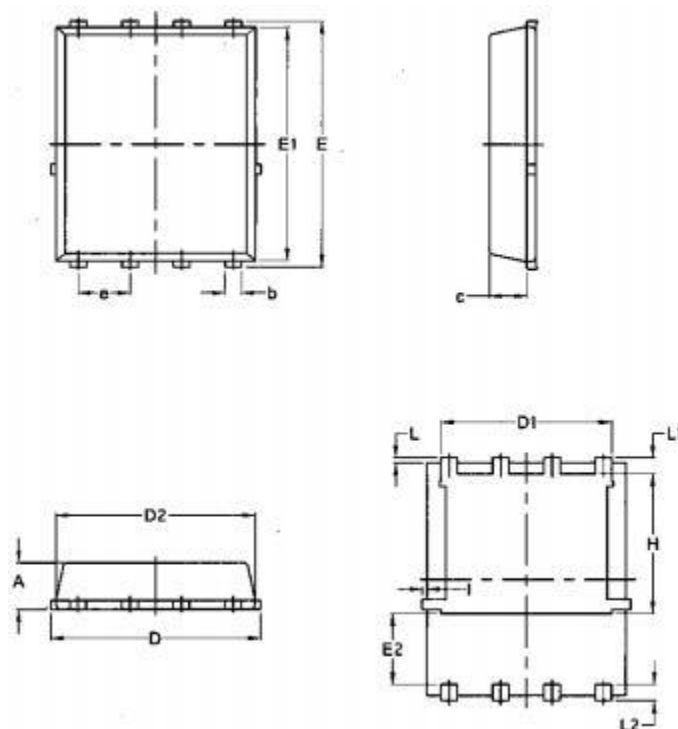


Fig.11 Unclamped Inductive Switching Wave

Package Mechanical Data-PDFN5*6-8L-JQ Single


Symbol	Common			
	mm		Inch	
	Mim	Max	Min	Max
A	1.03	1.17	0.0406	0.0461
b	0.34	0.48	0.0134	0.0189
c	0.824	0.0970	0.0324	0.082
D	4.80	5.40	0.1890	0.2126
D1	4.11	4.31	0.1618	0.1697
D2	4.80	5.00	0.1890	0.1969
E	5.95	6.15	0.2343	0.2421
E1	5.65	5.85	0.2224	0.2303
E2	1.60	/	0.0630	/
e	1.27 BSC		0.05 BSC	
L	0.05	0.25	0.0020	0.0098
L1	0.38	0.50	0.0150	0.0197
L2	0.38	0.50	0.0150	0.0197
H	3.30	3.50	0.1299	0.1378
I	/	0.18	/	0.0070

Package Marking and Ordering Information

Product ID	Pack	Marking	Qty(PCS)
TAPING	PDFN5*6-8L		5000